TelePix2

A HV-CMOS sensor for Fast Timing and ROI Triggering

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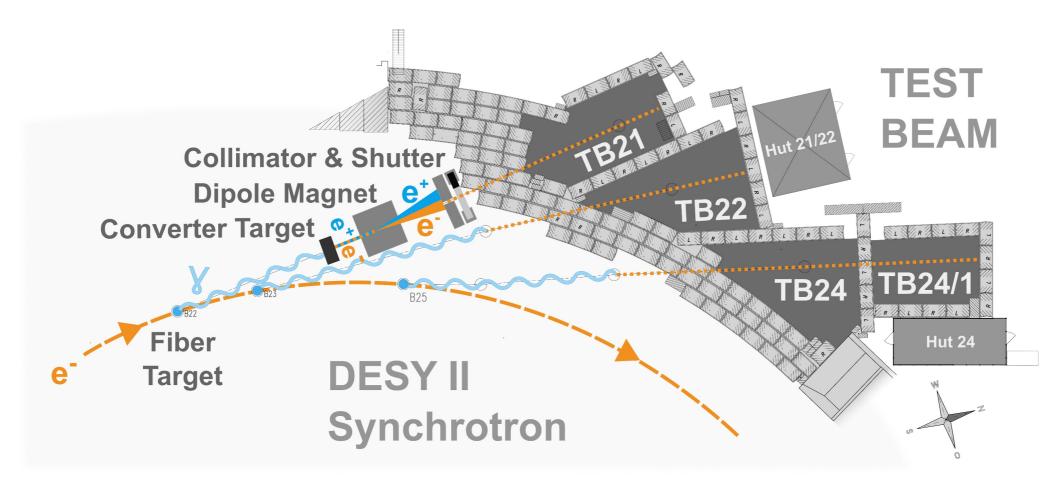
DPG Spring Meeting, Göttingen, 04/04/24





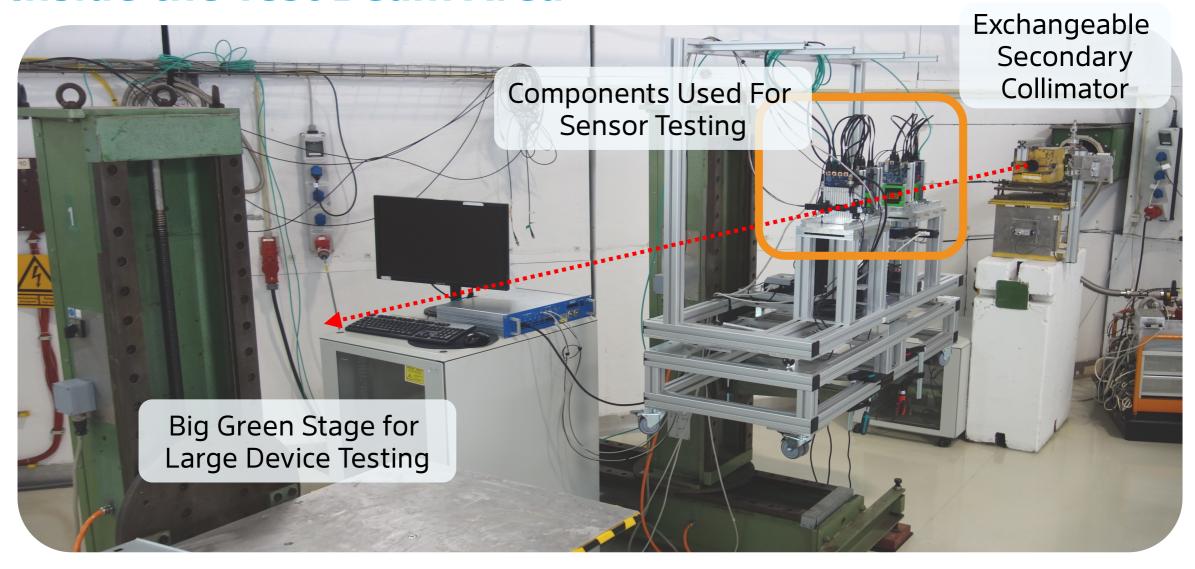


The DESY II Test Beam Facility



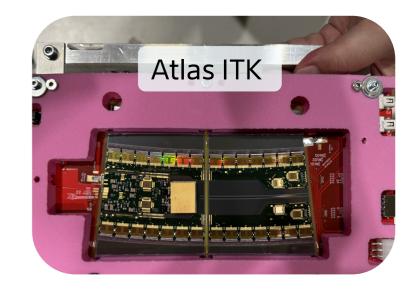
- → detector characterisation
- \rightarrow e⁻ or e⁺ 1-6 GeV/c

Inside the Test Beam Area



Device Under Test

Measurements include efficiency, spatial and timing resolution or calibration Range of different sizes under test

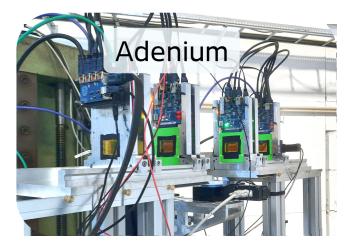


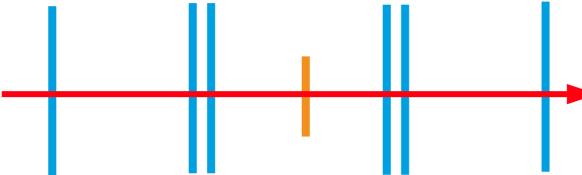
Electron Beam



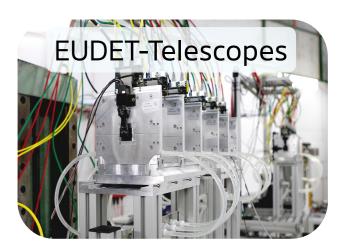
Telescope Planes

Multiple sensor planes Allow precise track reconstruction



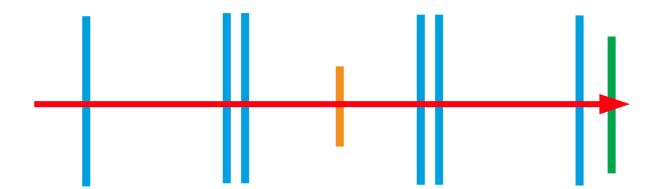


Device Under Test Electron Beam

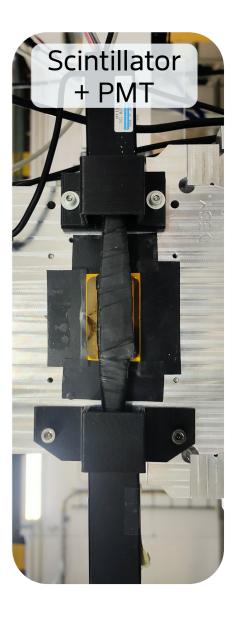


Trigger

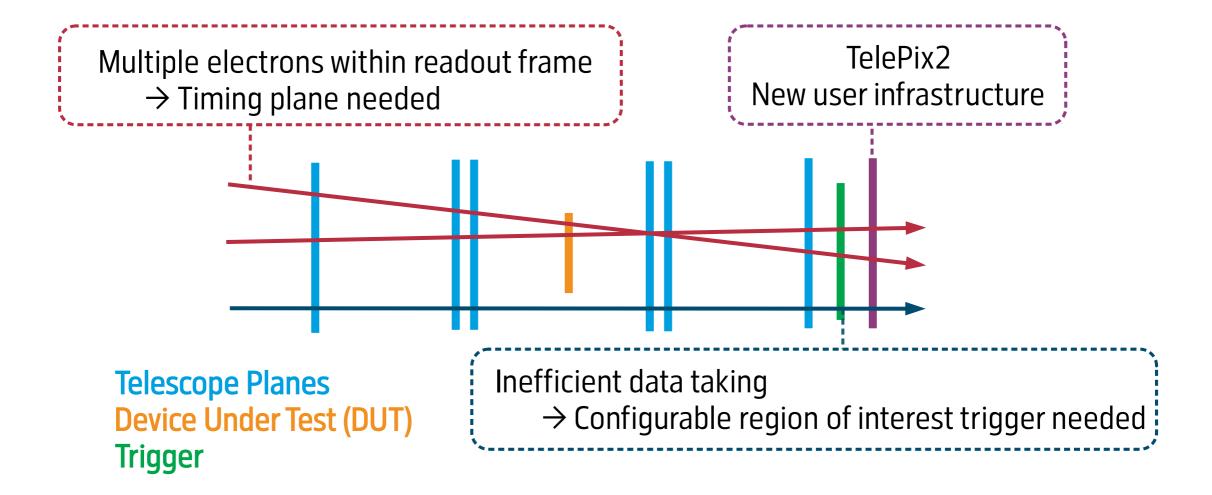
Tag the presence of particles Important for event based readout



Telescope Planes
Device Under Test
Electron Beam



Timing and ROI Triggering Plane



TelePix2

Key Features

- 180 nm HV-CMOS process of TSI
- 1) Fast user-configurable ROI trigger
- 2) Hit position with a 4 ns timestamp

• Pitch: 165 x 25 μm²

• Pixels: 120 x 400

Active Area: 2 x 1 cm²

TelePix2 reference paper on the arxiv

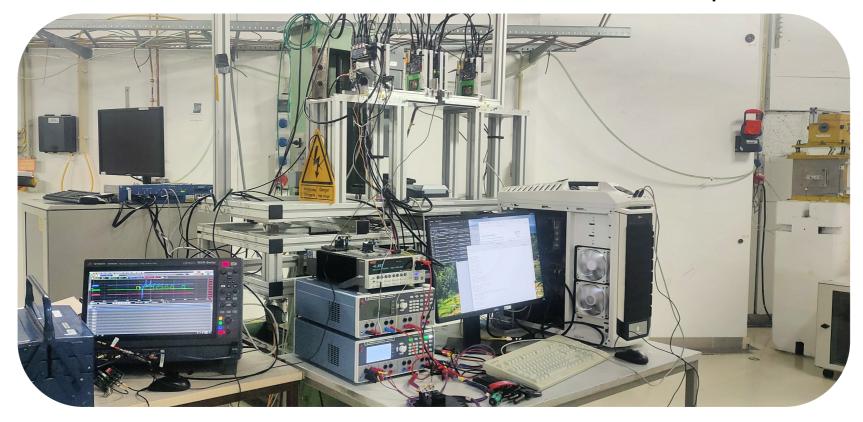


DESY Test Beam Campaign



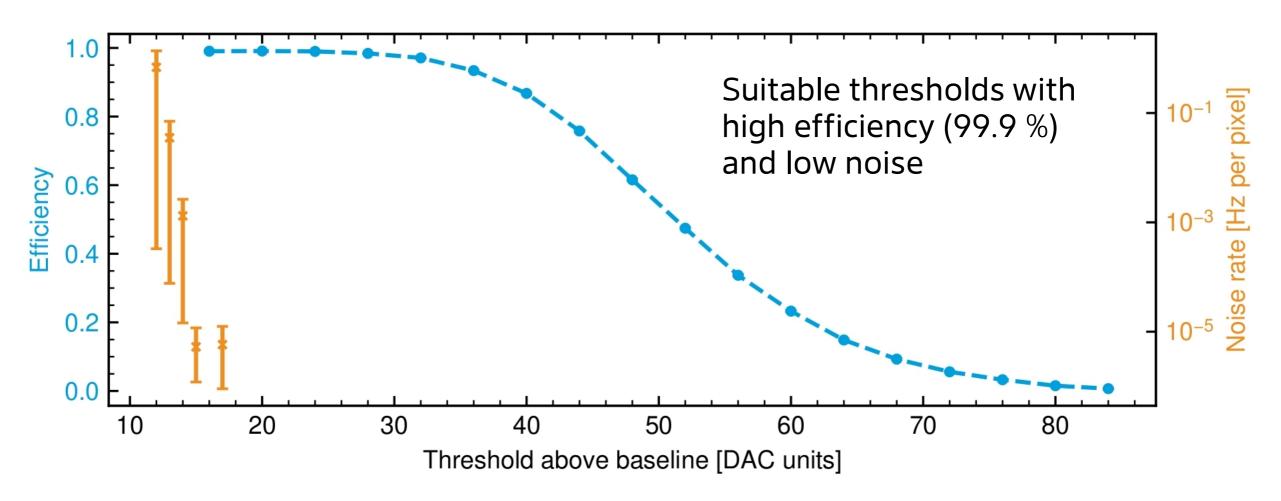


4 GeV electron beam
The TelePix2 sensor had a thickness ~ 740 μm.

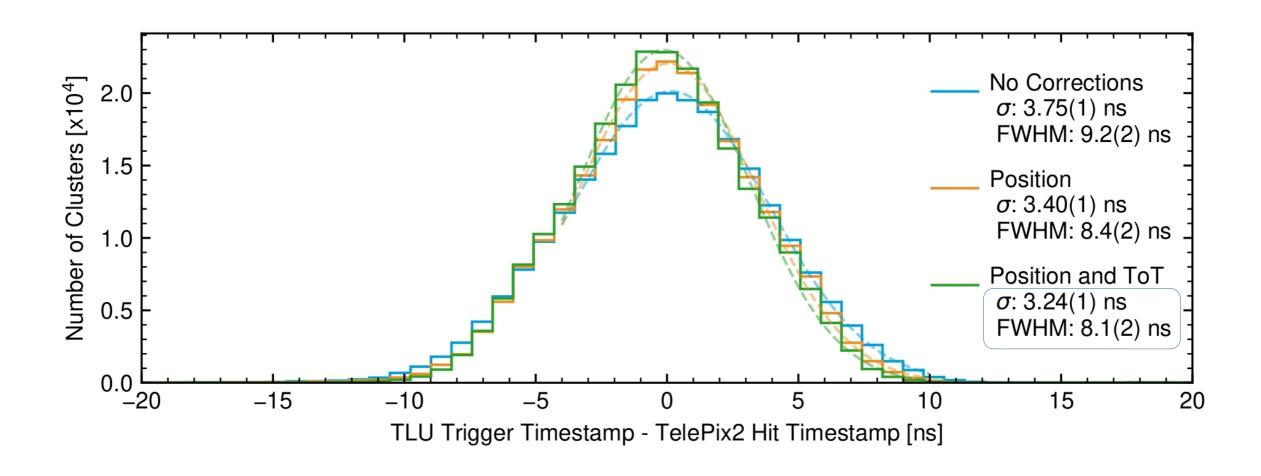


Analysis was carried out using the test beam reconstruction framework Corryvreckan.

Efficiency and Noise (Cooled Operation)



Time Resolution After Corrections



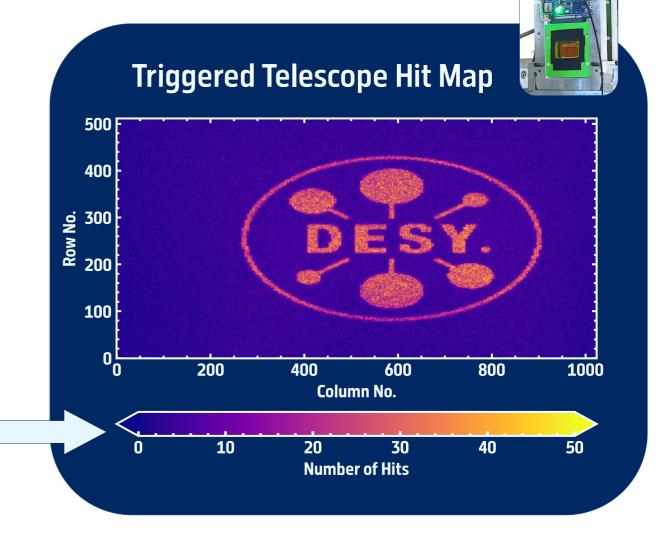
Fast Hit-OR Trigger and Masking Capabilities



Trigger Signal
(generated on chip then fed externally)

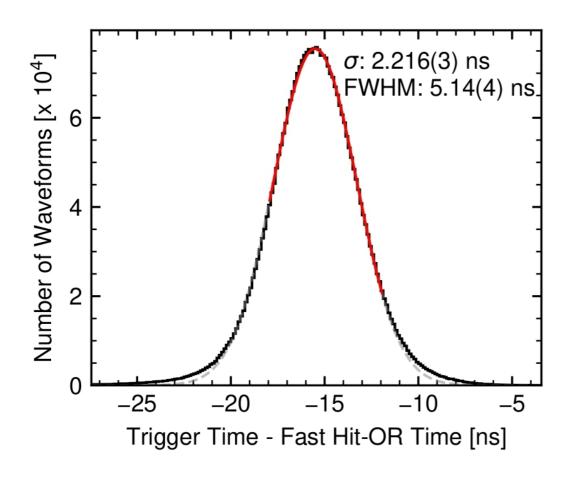
Rise time ~ 20 ns

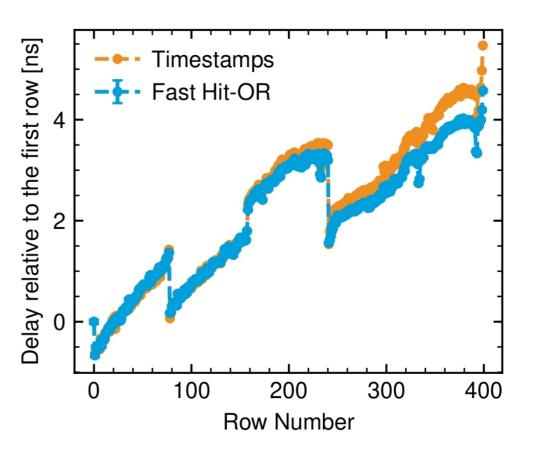
Voltage ~ 1.4 V



Fast Hit-OR Trigger Time Resolution

Timing Performance of the TelePix2 Trigger via Oscilloscope Waveforms



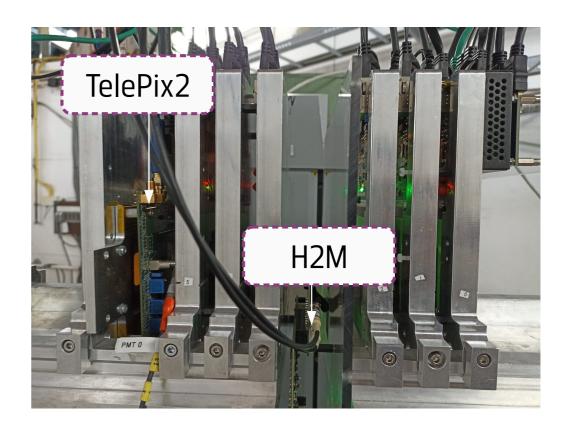


User Operation

New infrastructure at the DESY II Test Beam facility as **both** a ROI triggering and timing plane

User groups including RD50-MPW4, Atlas-ITK and Tangerine

Existing module within Corryvreckan for easy integration into analysis workflows



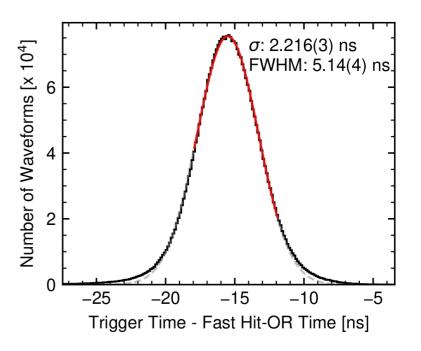
Summary

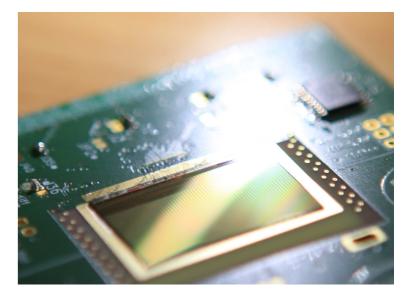
- TelePix2 developed for the DESY II Test Beam Facility
- Efficiency above 99 %
- Time resolution below 4 ns
- Trigger time resolution below 3 ns

Outlook

- Trimming performance currently being evaluated
- Aiming to equip all beamlines

The measurements leading to these results have been performed at the Test Beam Facility at DESY Hamburg (Germany), a member of the Helmholtz Association (HGF)





Appendix

TelePix2

Key Features

- 180 nm HV-CMOS process of TSI
- Fast user-configurable ROI trigger
- 4 ns timestamp
- A low material budget compared to hybrid sensors
- 3-bit trimming
- Amplifier and comparator within pixel
- Self-triggered readout with zero suppression

• Pitch: 165 x 25 μm²

• Pixels: 120 x 400

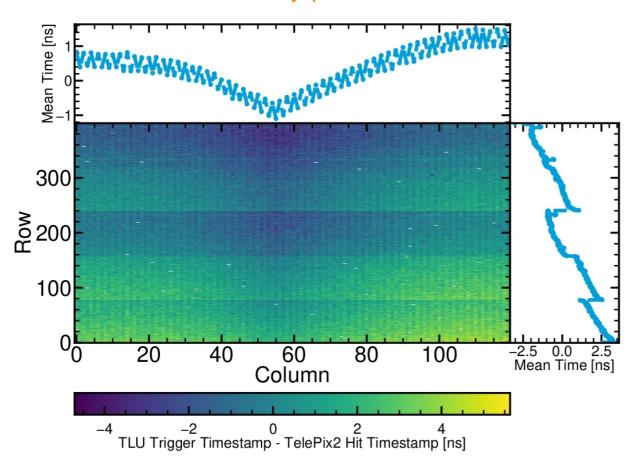
Active Area: 2 x 1 cm²

TelePix2 reference paper on the arxiv

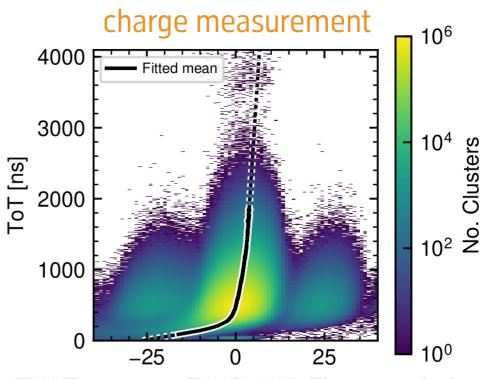


Position and Charge Time Delay

Time Delay per Pixel



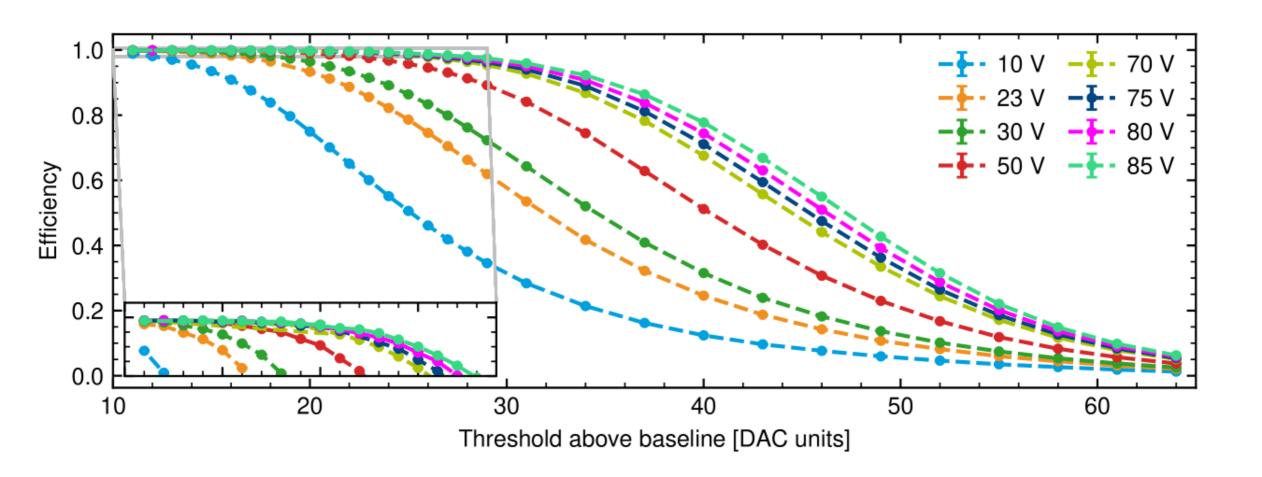
Time Delay for corresponding



TLU Timestamp - TelePix2 Hit Timestamp [ns]

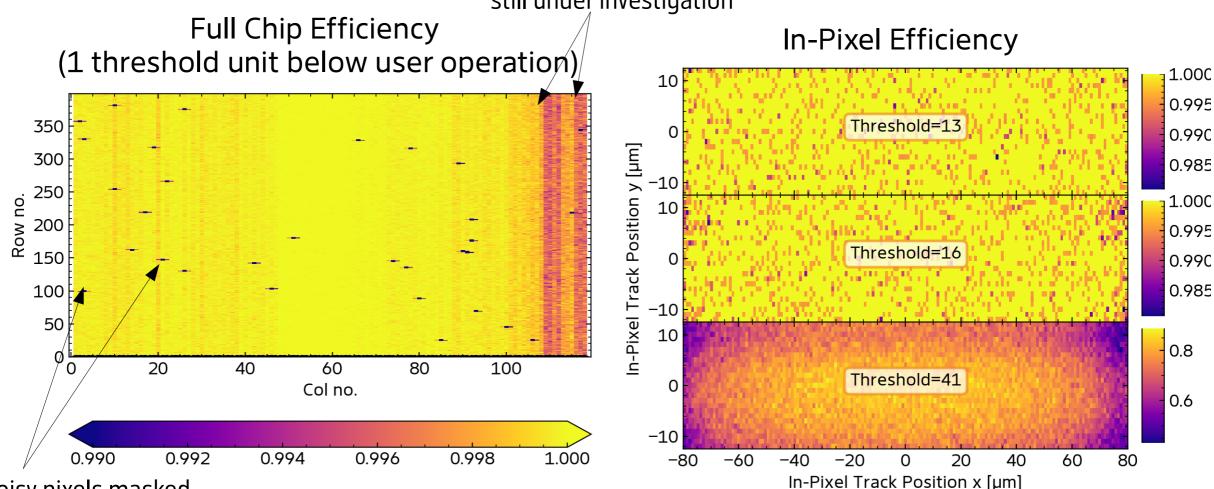
18

Efficiency vs Threshold



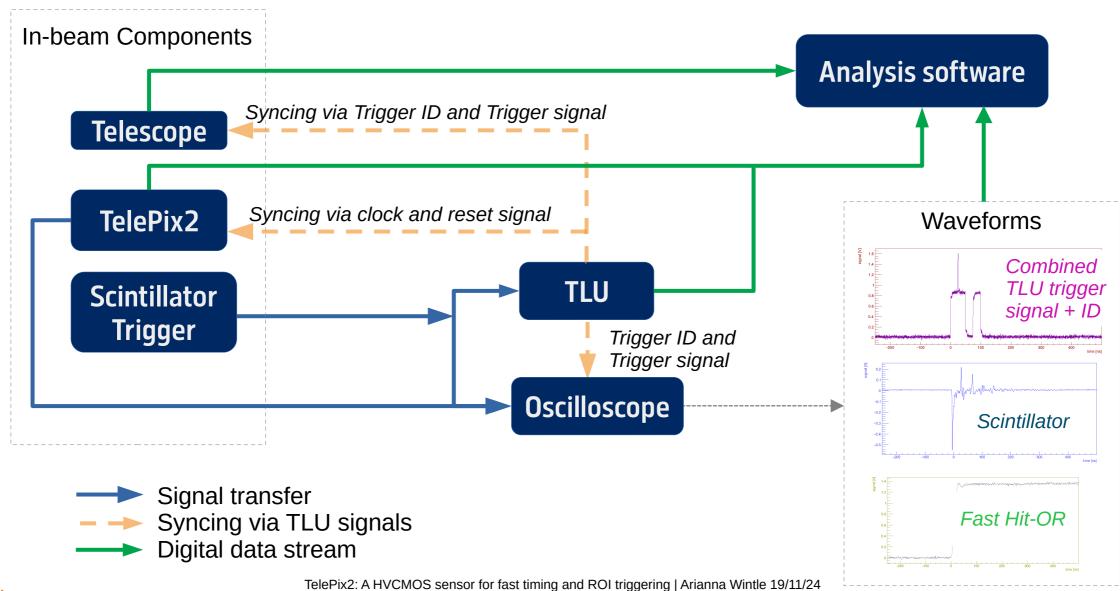
Efficiency

Slightly lower efficiency (< 1 %) columns still under investigation

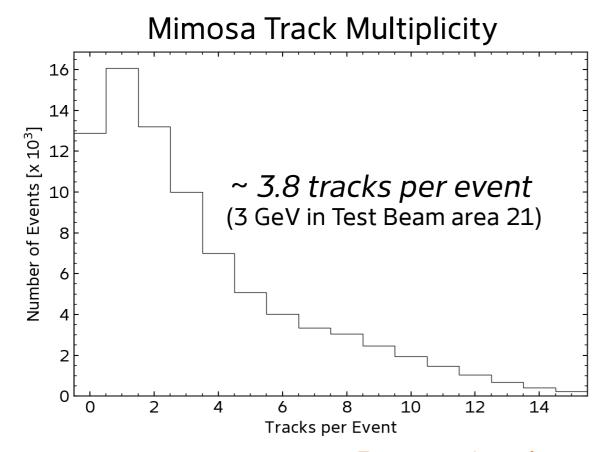


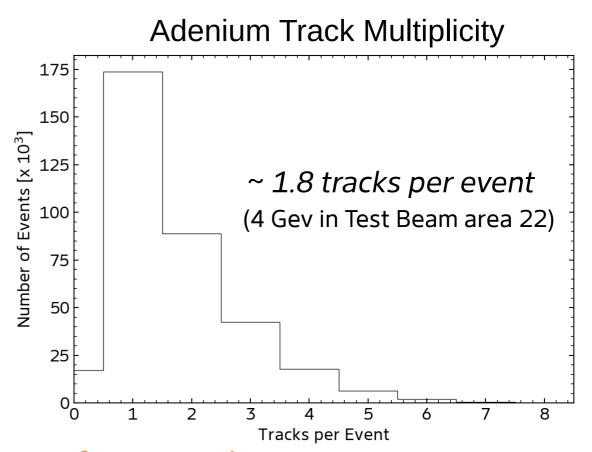
Noisy pixels masked online

Data Collection



Track Multiplicity

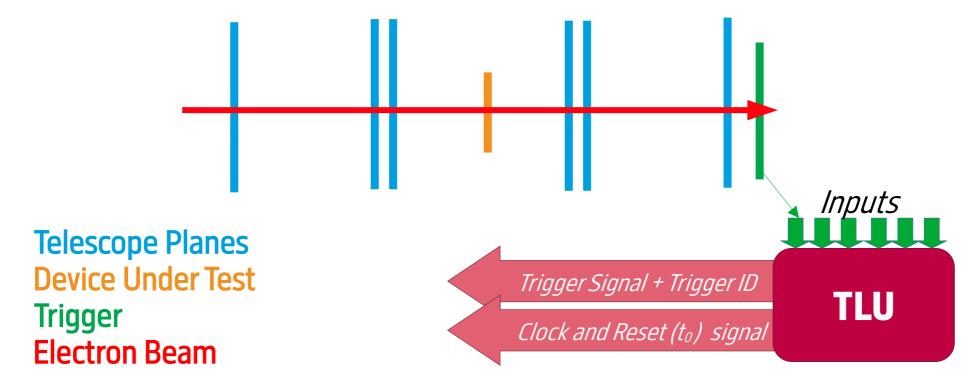




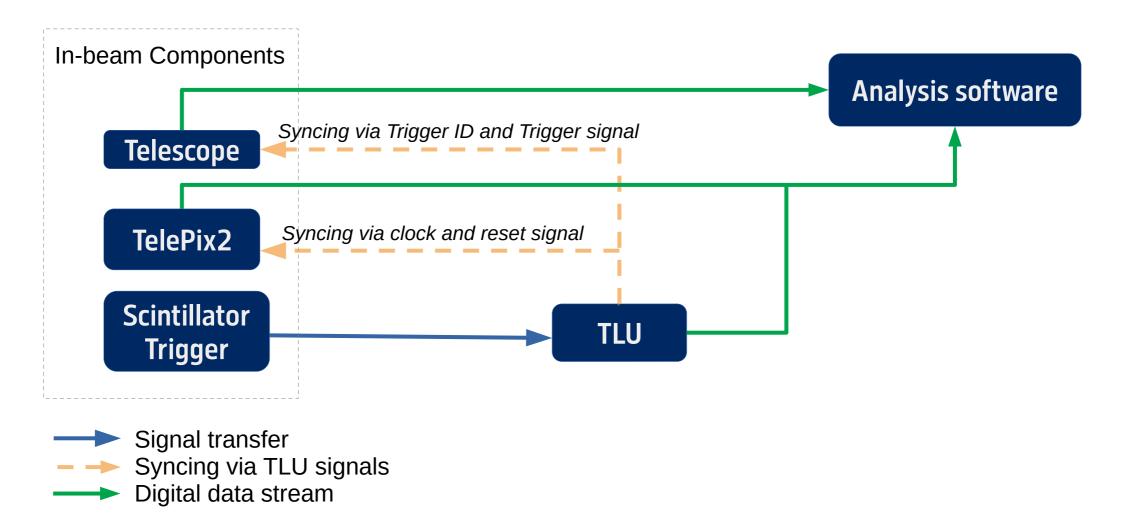
Rate varies dependent on factors such as: which beamline is in use, selected energy and target position The plots above should only be taken as a rough guide

Trigger Logic Unit (TLU)

Trigger on an arbitrary logical combination of 6 triggering inputs Synchronisation of multiple devices



Data Collection

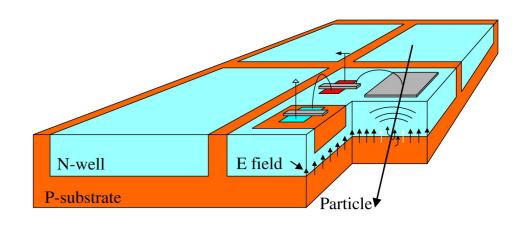


High-Voltage Monolithic Active Pixel Sensors HV-MAPS

- Hybrid sensors bump bond a separate readout and sensor chip together
 - Can be costly to manufacture and have a high material budget
- Monolithic sensors integrate readout and sensor onto one chip:
 - But charge collection via diffusion → too slow for high rate applications

HV-MAPS embed readout inside pixel electrode

- Higher biasing voltage → collection via drift (faster)
- Can result in improved:
 - → Signal amplitude
 - → Charge collection speed
 - → Radiation tolerance



Ivan Perić, NIM 582 (2007) 876-885